MSKSEMI 美森科













ESD

TVS

TSS

MOV

GDT

PIFD

1N4001W-1N4007W

Product specification





FEATURES

- Ideal for surface mount applications
- Easy pick and place
- Built-in strain relief
- High surge current capability

MECHANICAL DATA

Case: Molded plastic

• Epoxy: UL 94V-0 rate flame retardant

Terminals: Solder plated, solderable per MIL-STD-202F,

method 208 guranteed

Polarity: Color band denotes cathode end

Mounting position: Any

Reference News

| PACKAGE OUTLINE | Circuit | PINNING | | |
|-----------------|-----------|---------|-------------|--|
| 0 | | PIN | DESCRIPTION | |
| | SOD-123FL | 1 | Cathode | |
| l SOD-123FL | | 2 | Anode | |

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 2.5 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 % .

| Parameter | | SYMBOLS | 1N4001W A1 | 1N4002W A2 | 1N4003W A3 | 1N4004W A4 | 1N4005W A5 | 1N4006W A6 | 1N4007W A7 | UNITS |
|---|-------------------|------------------|---------------|---------------|---------------|---------------|---------------|---------------|---------------|-------|
| Maximum repetitive peak reverse vo | ltage | V _{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | VOLTS |
| Maximum RMS voltage | | VRMS | 35 | 70 | 140 | 280 | 420 | 560 | 700 | VOLTS |
| Maximum DC blocking voltage | | VDC | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | VOLTS |
| Maximum average forward rectified of Ta=65 C (NOTE 1) | current at | I(AV) | | | | 1.0 | | | | Amp |
| Peak forward surge current 8.3ms single half sine-wave superim load (JEDEC Method) T _L =25 C | posed on rated | İFSM | | | | 25.0 | | | | Amps |
| Maximum instantaneous forward volta | age at 1.0 A | VF | | | | 1.0 | | | | Volts |
| Maximum DC reverse current at rated DC blocking voltage | Ta=25℃ Ta=125℃ | lR | 10.0 50.0 | | | | μА | | | |
| Typical junction capacitance (NOTE | 2) | J | | | | 4 | | | | pF |
| Typical thermal resistance (NOTE 3) | | R9JA | | | | 180 | | | | K/W |
| Operating junction and storage temp | erature range | ТЈ,Тѕтс | -65 to +150 | | $^{\circ}$ | | | | | |

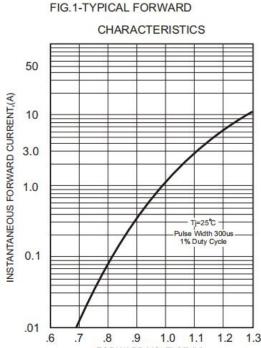
Note: 1. Averaged over any 20ms period.

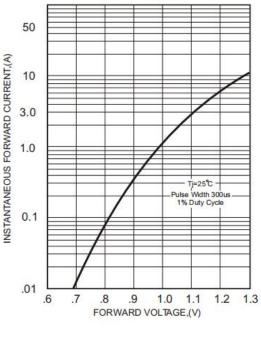
^{2.}Measured at 1MHz and applied reverse voltage of 4.0V D.C.

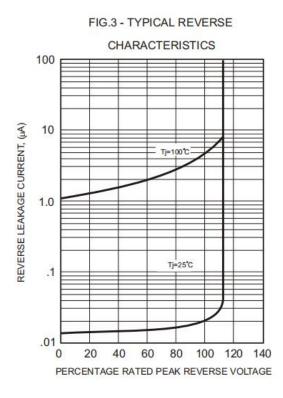
^{3.} Thermal resistance from junction to ambient at 0.375" (9.5mm)lead length, P.C.B. mounted

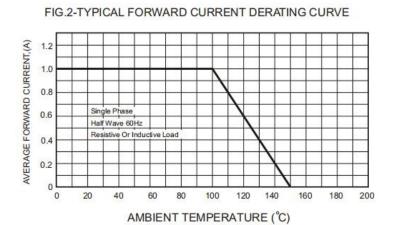


ELECTRICAL CHARACTERISTICS CURVE

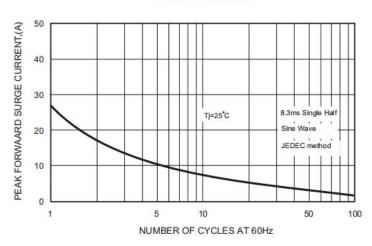


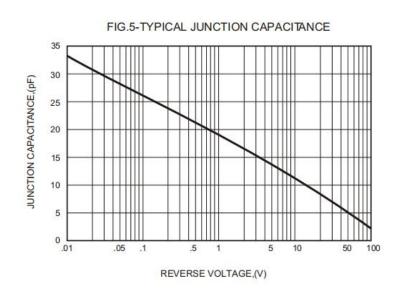






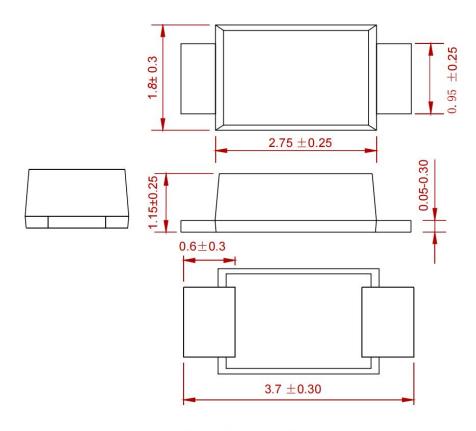






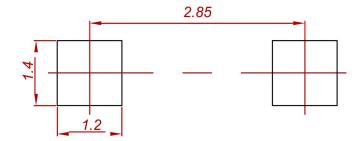


PACKAGE MECHANICAL DATA



Dimensions in millimeters

Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

| P/N | PKG | QTY |
|-----------------|-----------|------|
| 1N4001W-1N4007W | SOD-123FL | 3000 |



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